

# **AUIPS71411G**

#### **CURRENT SENSE HIGH SIDE SWITCH**

#### **Features**

- Suitable 24V battery operation
- Over current shutdown
- Over temperature shutdown
- Current sensing
- Active clamp
- Low current
- ESD protection
- Optimized Turn On/Off for EMI

#### **Applications**

- Solenoid
- 24V loads for trucks

#### **Description**

The AUIPS71411G is a fully protected four terminal high side switch specifically designed for 24V battery application. It features current sensing, over-current, over-temperature, ESD protection and drain to source active clamp. When the input voltage Vcc - Vin is higher than the specified threshold, the output power Mosfet is turned on. When the Vcc - Vin is lower than the specified Vil threshold, the output Mosfet is turned off. The Ifb pin is used for current sensing.

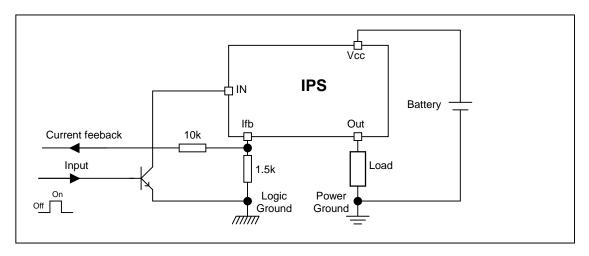
### **Product Summary**

Rds(on)  $100m\Omega$  max. Vclamp 65V Current shutdown 5A min.

#### **Packages**



### **Typical Connection**





## Qualification Information<sup>†</sup>

| tualification information |                  |  |   |  |  |  |  |
|---------------------------|------------------|--|---|--|--|--|--|
|                           |                  | Automotive (per AEC-Q100 <sup>††</sup> )         |   |  |  |  |  |
| Qualification L           | evel             | Comments: This family qualification. IR's Indust | Comments: This family of ICs has passed an Automotive qualification. IR's Industrial and Consumer qualification level is granted by extension of the higher Automotive level. |  |  |  |  |
| Moisture Sens             | itivity Level    | SOIC-8L  | MSL2, 260°C<br>(per IPC/JEDEC J-STD-020)  |  |  |  |  |
|                           | Machine Model    | Class M2 (200 V)<br>(per AEC-Q100-003)           |   |  |  |  |  |
| ESD                       | Human Body Model |  | Class H1C (1500 V)<br>(per AEC-Q100-002)  |  |  |  |  |
| Charged Device Model      |                  | Class C5 (1000 V)<br>(per AEC-Q100-011)          |   |  |  |  |  |
| IC Latch-Up Te            | est              | (p   | ClassII, Level A<br>er AEC-Q100-004)  |  |  |  |  |
| RoHS Complia              | nnt              | Yes  |   |  |  |  |  |

Qualification standards can be found at International Rectifier's web site <a href="http://www.irf.com/">http://www.irf.com/</a> Exceptions to AEC-Q100 requirements are noted in the qualification report.



**Absolute Maximum Ratings**Absolute maximum ratings indicate sustained limits beyond which damage to the device may occur. All voltage parameters

are referenced to the ground lead. (Tambient=25°C unless otherwise specified).

| Symbol       | Parameter  | Min.   | Max.    | Units |
|--------------|--|--------|---------|-------|
| Vout         | Maximum output voltage   | Vcc-60 | Vcc+0.3 | V     |
| Vcc-Vin max. | Maximum Vcc voltage  | -16    | 65      | V     |
| lifb, max.   | Maximum feedback current   | -50    | 10      | mA    |
| Vcc sc.      | Maximum Vcc voltage with short circuit protection see page 6         | _      | 50      | V     |
| Pd           | Maximum power dissipation (internally limited by thermal protection) |        |         | W     |
| Fu           | Rth=100°C/W  | _      | 1.25    | VV    |
| Tj max.      | Max. storage & operating junction temperature                        | -40    | 150     | °C    |

#### **Thermal Characteristics**

| Symbol | Parameter                                  | Тур. | Max. | Units |
|--------|--|------|------|-------|
| Rth1   | Thermal resistance junction to ambient SO8 | 100  | _    | °C/W  |

Recommended Operating Conditions

These values are given for a quick design. For operation outside these conditions, please consult the application notes.

| Symbol | Parameter  | Min. | Max. | Units |
|--------|--|------|------|-------|
| lout   | Continuous output current, Tambient=85°C, Tj=125°C |      |      | ۸     |
|        | Rth=100°C/W  | _    | 1.5  | A     |
| RIfb   | Ifb resistor                                       | 1.5  | _    | kΩ    |



#### **Static Electrical Characteristics**

Tj=25°C, Vcc=28V (unless otherwise specified)

| Symbol   | Parameter                           | Min. | Тур. | Max. | Units | Test Conditions     |
|----------|-------------------------------------|------|------|------|-------|---------------------|
| Vcc op.  | Operating voltage                   | 6    | _    | 60   | V     |                     |
| Rds(on)  | ON state resistance Tj=25°C         |      | 75   | 100  | 0     | lds=2A              |
|          | ON state resistance Tj=150°C(2)     | _    | 135  | 180  | mΩ    | lus=2A              |
| Icc off  | Supply leakage current              | _    | 1    | 3    |       | Vin=Vcc / Vifb=Vgnd |
| lout off | Output leakage current              | _    | 1    | 3    | μA    | Vout=Vgnd           |
| I in on  | Input current while on              | 0.6  | 1.6  | 3    | mA    | Vcc-Vin=28V         |
| V clamp1 | Vcc to Vout clamp voltage 1         | 60   | 64   | _    |       | Id=10mA             |
| V clamp2 | Vcc to Vout clamp voltage 2         | 60   | 65   | 72   |       | Id=6A see fig. 2    |
| Vih(1)   | High level Input threshold voltage  | _    | 3    | 4.5  | \/    | Id=10mA             |
| Vil(1)   | Low level Input threshold voltage   | 1.5  | 2.3  | _    | \ \ \ |                     |
|          | Forward body diode voltage Tj=25°C  |      | 0.8  | 0.9  |       | If=1A               |
|          | Forward body diode voltage Tj=125°C | _    | 0.65 | 0.75 |       |                     |

<sup>(1)</sup> Input thresholds are measured directly between the input pin and the tab.

#### **Switching Electrical Characteristics**

Vcc=28V, Resistive load=27Ω, Ti=25°C

| 101 = 01,1101011111111111111111111111111 |                                  |      |      |      |       |                 |
|--|----------------------------------|------|------|------|-------|-----------------|
| Symbol                                   | Parameter                        | Min. | Тур. | Max. | Units | Test Conditions |
| Tdon                                     | Turn on delay time to 20%        | 4    | 10   | 20   | us    |                 |
| Tr                                       | Rise time from 20% to 80% of Vcc | 2    | 5    | 10   | μδ    | See fig. 1      |
| Tdoff                                    | Turn off delay time              | 20   | 40   | 80   | 110   | See lig. 1      |
| Tf                                       | Fall time from 80% to 20% of Vcc | 2.5  | 5    | 10   | μs    |                 |

# **Protection Characteristics**

| Symbol  | Parameter  | Min.   | Тур. | Max. | Units | Test Conditions        |
|---------|--|--------|------|------|-------|------------------------|
| Tsd     | Over temperature threshold                                 | 150(2) | 165  | _    | °C    | See fig. 3 and fig. 11 |
| Isd     | Over-current shutdown                                      | 5      | 7    | 10   | Α     | See fig. 3 and page 6  |
| I fault | Ifb after an over-current or an over-temperature (latched) | 2.7    | 3.3  | 4    | mA    | See fig. 3             |

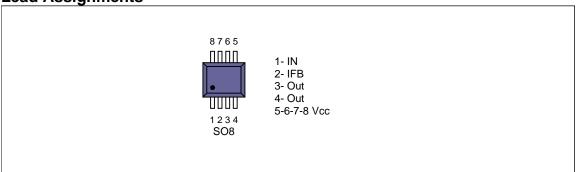
**Current Sensing Characteristics** 

| Symbol      | Parameter                                  | Min. | Тур. | Max. | Units | Test Conditions    |  |
|-------------|--|------|------|------|-------|--------------------|--|
| Ratio       | I load / Ifb current ratio                 | 2000 | 2400 | 2800 |       | Iload=2A           |  |
| Ratio_TC    | I load / Ifb variation over temperature(2) | -5%  | 0    | +5   | %     | Tj=-40°C to +150°C |  |
| I offset    | Load current offset                        | -0.2 | 0    | 0.2  | Α     | lout<2A            |  |
| Ifb leakage | Ifb leakage current                        | 0    | 8    | 100  | μA    | lout=0A            |  |

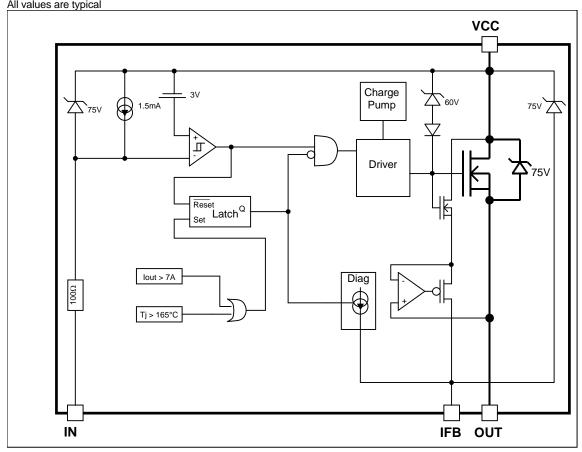
<sup>(2)</sup> Guaranteed by design



**Lead Assignments** 



# Functional Block Diagram All values are typical





#### **Truth Table**

| Op. Conditions       | Input | Output | Ifb pin voltage      |
|----------------------|-------|--------|----------------------|
| Normal mode          | Н     | L      | 0V                   |
| Normal mode          | L     | Н      | I load x Rfb / Ratio |
| Open load            | Н     | L      | 0V                   |
| Open load            | L     | Н      | 0V                   |
| Short circuit to GND | Н     | L      | 0V                   |
| Short circuit to GND | L     | L      | V fault (latched)    |
| Over temperature     | Н     | Ĺ      | 0V                   |
| Over temperature     | L     | L      | V fault (latched)    |

### **Operating voltage**

Maximum Vcc voltage: this is the maximum voltage before the breakdown of the IC process.

**Operating voltage**: This is the Vcc range in which the functionality of the part is guaranteed. The Q100 qualification is run at the maximum operating voltage specified in the datasheet.

#### Reverse battery

During the reverse battery the Mosfet is kept off and the load current is flowing into the body diode of the power Mosfet. Power dissipation in the IPS:  $P = I \log d * Vf$ 

If the power dissipation is too high in Rifb, a diode in serial can be added to block the current.

The transistor used to pull-down the input should be a bipolar in order to block the reverse current. The 100ohm input resistor can not sustain continuously 16V (see Vcc-Vin max. in the Absolute Maximum Ratings section)

#### **Active clamp**

The purpose of the active clamp is to limit the voltage across the MOSFET to a value below the body diode break down voltage to reduce the amount of stress on the device during switching.

The temperature increase during active clamp can be estimated as follows:

$$\Delta_{\text{Ti}} = P_{\text{CL}} \cdot Z_{\text{TH}} (t_{\text{CLAMP}})$$

Where:  $Z_{TH}(t_{CLAMP})$  is the thermal impedance at  $t_{CLAMP}$  and can be read from the thermal impedance curves given in the data sheets

 $P_{CL} = V_{CL} \cdot I_{CLavg}$ : Power dissipation during active clamp

 $V_{\text{CL}} = 65V$ : Typical  $V_{\text{CLAMP}}$  value.

 $I_{\text{CLavg}} = \frac{I_{\text{CL}}}{2}$  : Average current during active clamp

 $t_{\text{CL}} = \frac{I_{\text{CL}}^{-}}{\left|\frac{di}{dt}\right|} : \text{Active clamp duration}$ 

$$\frac{di}{dt} = \frac{V_{Battery} - V_{CL}}{L} : Demagnetization current$$

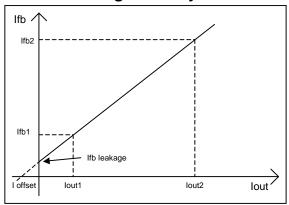
Figure 9 gives the maximum inductance versus the load current in the worst case : the part switch off after an over temperature detection. If the load inductance exceed the curve, a free wheeling diode is required.

#### **Over-current protection**

The threshold of the over-current protection is set in order to guaranteed that the device is able to turn on a load with an inrush current lower than the minimum of lsd. Nevertheless for high current and high temperature the device may switch off for a lower current due to the over-temperature protection (see Figure 11).



#### **Current sensing accuracy**



The current sensing is specified by measuring 3 points:

- Ifb1 for lout1
- Ifb2 for lout2
- Ifb leakage for lout=0

Then the parameters of the datasheet are computed by the following formula:

Ratio = (lout2 - lout1)/(lfb2 - lfb1)

I offset = Ifb1 x Ratio - lout1

This allows the designer to evaluate the Ifb for any lout value using :

Ifb = ( lout + I offset ) / Ratio if Ifb > Ifb leakage

For some applications, a calibration is required. In that case, the accuracy of the system will depends on the variation of the I offset and the ratio over the temperature range. The ratio variation is given by Ratio TC specified in page 3.

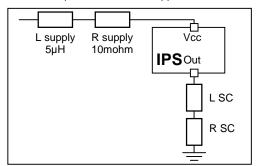
The loffset variation depends directly of the Rdson:

I offset@-40°C= I offset@25°C / 0.8

I offset@150°C= I offset@25°C / 1.9

### Maximum Vcc voltage with short circuit protection

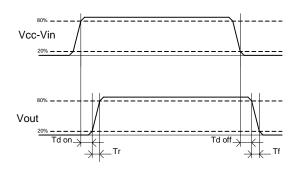
The maximum Vcc voltage with short circuit is the maximum voltage for which the part is able to protect itself under test conditions representative of the application. 2 kind of short circuits are considered: terminal and load short circuit.



|             | L SC   | R SC     |
|-------------|--------|----------|
| Terminal SC | 0.1 μΗ | 10 mohm  |
| Load SC     | 10 µH  | 100 mohm |

# **AUIPS71411G**





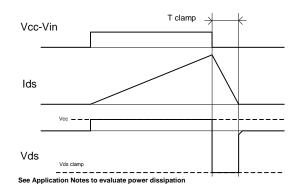


Figure 1 – IN rise time & switching definitions

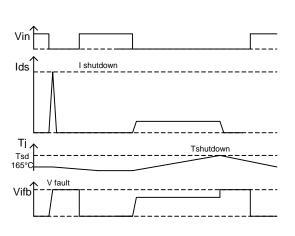


Figure 3 – Protection timing diagram

Figure 2 - Active clamp waveforms

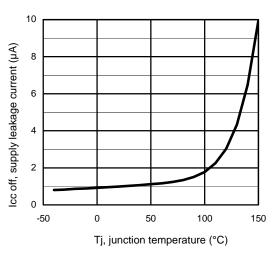


Figure 4 – Icc off (µA) Vs Tj (°C)

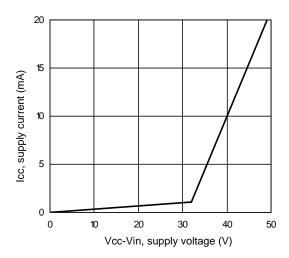


Figure 5 - Icc (mA) Vs Vcc-Vin (V)

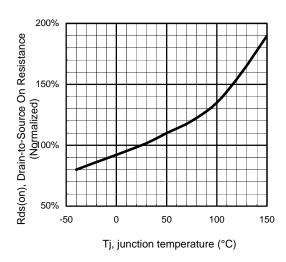


Figure 7 - Normalized Rds(on) (%) Vs Tj (°C)

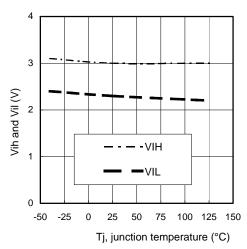


Figure 6 - Vih and Vil (V) Vs Tj (°C)

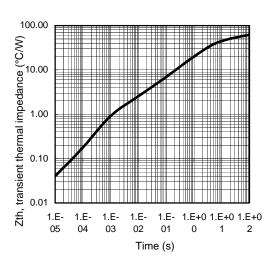
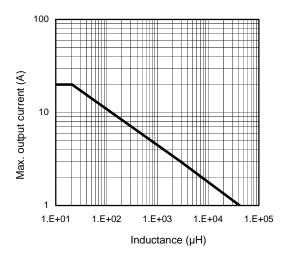


Figure 8 – Transient thermal impedance (°C/W) Vs time (s)



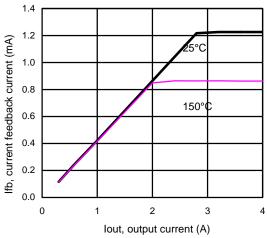


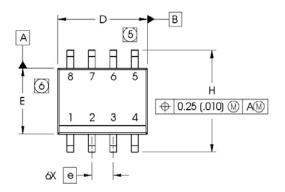
Figure 9 – Max. lout (A) Vs inductance (µH)

Figure 10 – Ifb (mA) Vs lout (A)



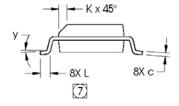
#### Case Outline - SO-8

Dimensions are shown in millimeters (inches)



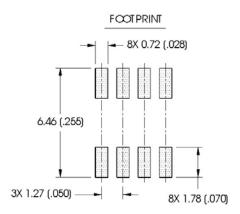
| 8X b A1 0.10 (.004)             |
|---------------------------------|
| ⊕   0.25 (.010) (M)   C   A   B |

| DIM   | INC        | HES   | MILLIM  | ETERS |
|-------|------------|-------|---------|-------|
| DIIVI | MIN        | MAX   | MIN     | MAX   |
| Α     | .0532      | .0688 | 1.35    | 1.75  |
| A1    | .0040      | .0098 | 0.10    | 0.25  |
| b     | .013       | .020  | 0.33    | 0.51  |
| С     | .0075      | .0098 | 0.19    | 0.25  |
| D     | .189       | .1968 | 4.80    | 5.00  |
| Е     | .1497      | .1574 | 3.80    | 4.00  |
| е     | .050 BASIC |       | 1.27 B  | ASIC  |
| e1    | .025 B     | ASIC  | 0.635 1 | BASIC |
| Н     | .2284      | .2440 | 5.80    | 6.20  |
| К     | .0099      | .0196 | 0.25    | 0.50  |
| L     | .016       | .050  | 0.40    | 1.27  |
| У     | 0°         | 8°    | 0°      | 8°    |



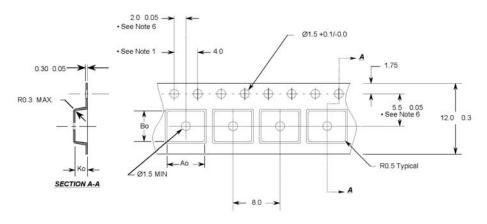
#### NOTES:

- DIMENSIONING & TOLERANGING PER ASME Y14.5M-1994.
- 2. CONTROLLING DIMENSION: MILLIMETER
- 3. DIMENSIONS ARE SHOWN IN MILLIMETERS (INCHES).
- 4. OUTLINE CONFORMS TO JEDEC OUTLINE MS-012AA.
- (5) DIMENSION DOES NOT INCLUDE MOLD PROTRUSIONS. MOLD PROTRUSIONS NOT TO EXCEED 0.15 (.006).
- (6) DIMENSION DOES NOT INCLUDE MOLD PROTRUSIONS. MOLD PROTRUSIONS NOT TO EXCEED 0.25 (.010).
- (7) DIMENSION IS THE LENGTH OF LEAD FOR SOLDERING TO A SUBSTRATE.





# Tape & Reel - SO-8



Ko = 2.1 mm

#### Notes:

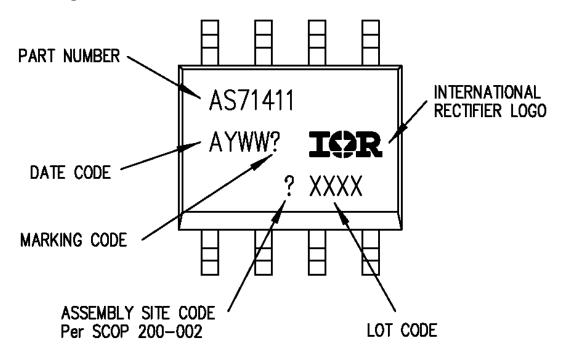
- 1. 10 sprocket hole pitch cumulative tolerance 0.2
   2. Camber not to exceed 1mm in 100mm
- 3. Material: Black Conductive Advantek Polystyrene 4. Ao and Bo measured on a plane 0.3mm above the
- 5. Ko measured from a plane on the inside bottom of the
- bottom of the pocket

Ao = 6.4 mm - All Dimensions in Millimeters -Bo = 5.2 mm

pocket to the top surface of the carrier.

6. Pocket position relative to sprocket hole measured as true position of pocket, not pocket hole.

# **Part Marking Information**



# **Ordering Information**

| Base Part Number | Package Type | Standard Pack |          | O-market - Boot Name |
|------------------|--------------|---------------|----------|----------------------|
|                  |              | Form          | Quantity | Complete Part Number |
| AUIPS71411G      | SO8          | Tube          | 95       | AUIPS71411G          |
|                  |              | Tape and reel | 2500     | AUIPS71411GTR        |



#### IMPORTANT NOTICE

Unless specifically designated for the automotive market, International Rectifier Corporation and its subsidiaries (IR) reserve the right to make corrections, modifications, enhancements, improvements, and other changes to its products and services at any time and to discontinue any product or services without notice. Part numbers designated with the "AU" prefix follow automotive industry and / or customer specific requirements with regards to product discontinuance and process change notification. All products are sold subject to IR's terms and conditions of sale supplied at the time of order acknowledgment.

IR warrants performance of its hardware products to the specifications applicable at the time of sale in accordance with IR's standard warranty. Testing and other quality control techniques are used to the extent IR deems necessary to support this warranty. Except where mandated by government requirements, testing of all parameters of each product is not necessarily performed.

IR assumes no liability for applications assistance or customer product design. Customers are responsible for their products and applications using IR components. To minimize the risks with customer products and applications, customers should provide adequate design and operating safeguards.

Reproduction of IR information in IR data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. Reproduction of this information with alterations is an unfair and deceptive business practice. IR is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of IR products or serviced with statements different from or beyond the parameters stated by IR for that product or service voids all express and any implied warranties for the associated IR product or service and is an unfair and deceptive business practice. IR is not responsible or liable for any such statements.

IR products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or in other applications intended to support or sustain life, or in any other application in which the failure of the IR product could create a situation where personal injury or death may occur. Should Buyer purchase or use IR products for any such unintended or unauthorized application, Buyer shall indemnify and hold International Rectifier and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that IR was negligent regarding the design or manufacture of the product.

IR products are neither designed nor intended for use in military/aerospace applications or environments unless the IR products are specifically designated by IR as military-grade or "enhanced plastic." Only products designated by IR as military-grade meet military specifications. Buyers acknowledge and agree that any such use of IR products which IR has not designated as military-grade is solely at the Buyer's risk, and that they are solely responsible for compliance with all legal and regulatory requirements in connection with such use.

IR products are neither designed nor intended for use in automotive applications or environments unless the specific IR products are designated by IR as compliant with ISO/TS 16949 requirements and bear a part number including the designation "AU". Buyers acknowledge and agree that, if they use any non-designated products in automotive applications, IR will not be responsible for any failure to meet such requirements.

For technical support, please contact IR's Technical Assistance Center http://www.irf.com/technical-info/

#### WORLD HEADQUARTERS:

233 Kansas St., El Segundo, California 90245 Tel: (310) 252-7105